



InGaN-based UV photodiode

Model **GS-UVV-3535LWI**

General Features:

- Indium Gallium Nitride Based Material
- Photovoltaic mode operation
- SMD 3535 ceramic inorganic package
- High responsivity and low dark current

Applications: UV LED Monitoring, UV radiation dose measurement, UV Curing

Specifications:

Parameters	Symbol	Value
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